MAINTENANCE MANUAL

LB14980 (DF1107 (DF1118 (IMTS)

138—174 MHz RF ASSEMBLY 19D416693G1, G2, G7, G8 AND MIXER/IF BOARD 19C320153G1

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DESCRIPTION

The RF Assembly uses five tuned helical resonators to provide front end RF selectivity with no gain. A UHS pre-amplifier assembly is available that can be used with the receiver to improve sensitivity.

The Mixer/IF board (MIF) uses the RF signal from the RF Assembly and the mixer injection frequency from the oscillator multiplier board to generate the IF frequency.

CIRCUIT ANALYSIS

RF ASSEMBLY

RF PRE-AMPLIFIER (Optional)

The pre-amplifier is present only in UHS receivers, and uses a dual-gate Field Effect Transistor (FET) to provide approximately 12 dB gain.

RF from the antenna is coupled through T2301 to Gate 1 of pre-amplifier Q2301. The primary of T2301 provides a 50 ohm input impedance. The amplified output at the drain terminal of Q2301 is coupled through T2302 and connected to J1 on Antenna Input board A301 through cable W2302. T2302 is tapped to provide a 50 ohm output impedance. P2301 connects to J501 on the MIF board for the regulated +10 Volt supply voltage.

ANTENNA INPUT A301/A301B

An RF signal from the antenna or UHS pre-amplifier is applied to A301 which provides an AC ground between vehicle ground and receiver A-. Resistor R1 prevents a static charge from building up on the vehicle antenna. The output of A301 is coupled

through five high Q helical resonators that provide the front end RF selectivity. The helicals are tuned to the incoming frequency by C301 through C305.

MIXER-IF

MIXER & CRYSTAL FILTER

The mixer uses a FET (Q501) as the active device. The FET mixer provides a high input impedance, high power gain, and an output relatively free of harmonics (low in intermodulation products).

In the mixer stage, RF from the helical resonators is coupled through L502 and C502 which matches the RF output to the gate of mixer Q501. Injection voltage from the multiplier-selectivity stages is inductively coupled through L501 to the source of the mixer. The 11.2 MHz mixer IF output signal is coupled from the drain of Q501 through a tuned circuit (L505 and C505) which matches the mixer output to the input of the fourpole monolithic crystal filter. The highlyselective crystal filter (FL501 and FL502) provides the first portion of the receiver IF selectivity. The output of the filter is coupled through impedance-matching network L520 and C523 to the IF amplifier.

Service Note: Variable capacitor C521 does not require adjustment when performing normal alignment. If the four-pole monolithic crystal filter is replaced, then adjustment of C521 is necessary for optimum IF response.

IF AMPLIFIER

IF amplifier Q520 is a dual-gate FET. The filter output is applied to Gate 1 of the amplifier, and the output is taken from the drain. The biasing on Gate 2 and the drain load determines the gain of the stage. The amplifier provides approximately 20 dB of IF gain.



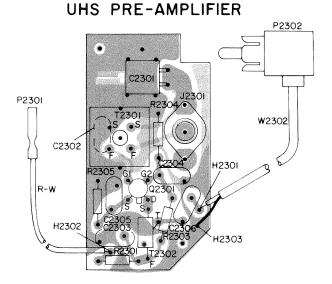
The output of Q520 is coupled through impedance matching network L521, and C528 and coupling capacitor C529 and feed-through capacitor C325 to the next IF stage on to the MIF switch in Dual Front End Applications.

Supply voltage for the RF amplifier and MIF board is supplied through feed-through capacitor C326.

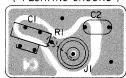
GENERAL ELECTRIC COMPANY+ MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS+LYNCHBURG, VIRGINIA 24502 U.S.A.

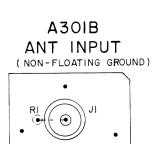


MIXER/IF BOARD 19C331099GI

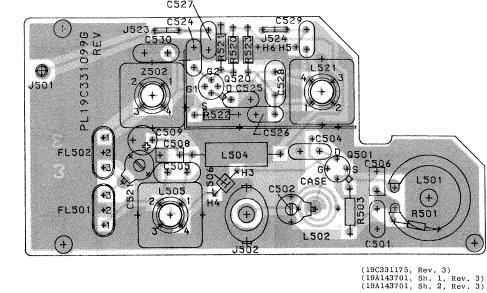


A30IA ANT INPUT (FLOATING GROUND)





(19B219679, Sh. 2, Rev. 2) (19B219679, Sh. 3, Rev. 2)





VIEW FROM LEAD END NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE. IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

LEAD IDENTIFICATION



VIEW FROM LEAD END NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE. IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

LEAD IDENTIFICATION FOR Q520

(+\\^A301 C326 C325

RF ASSEMBLY

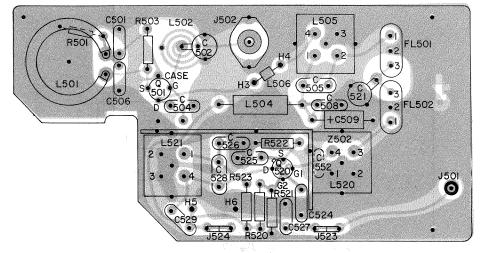
BOTTOM VIEW

(19D423618, Rev. 2)

- RUNS ON SOLDER SIDE RUNS ON BOTH SIDES RUNS ON COMPONENT SIDE

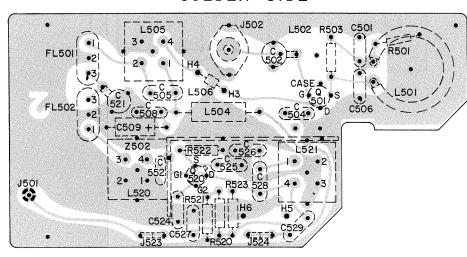
MIXER/IF BOARD 19C320I53GI

COMPONENT SIDE



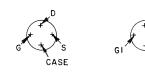
(19C321054, Sh. 2, Rev. 2) (19C321054, Sh. 3, Rev. 1)

SOLDER SIDE



(19C321054, Sh. 2, Rev.3)

Q520, Q2301



VIEW FROM CASE END

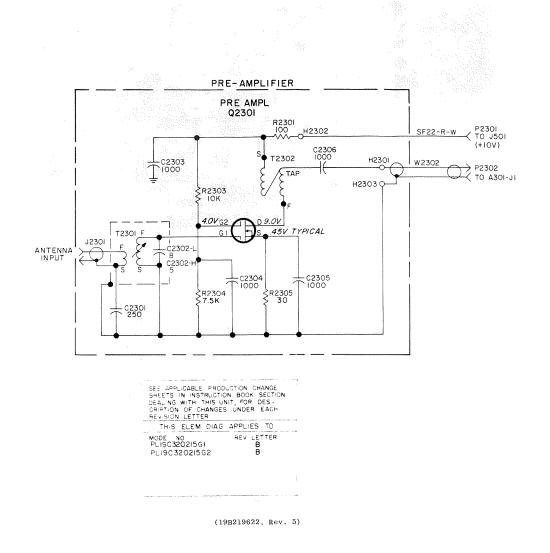
LEAD IDENTIFICATION

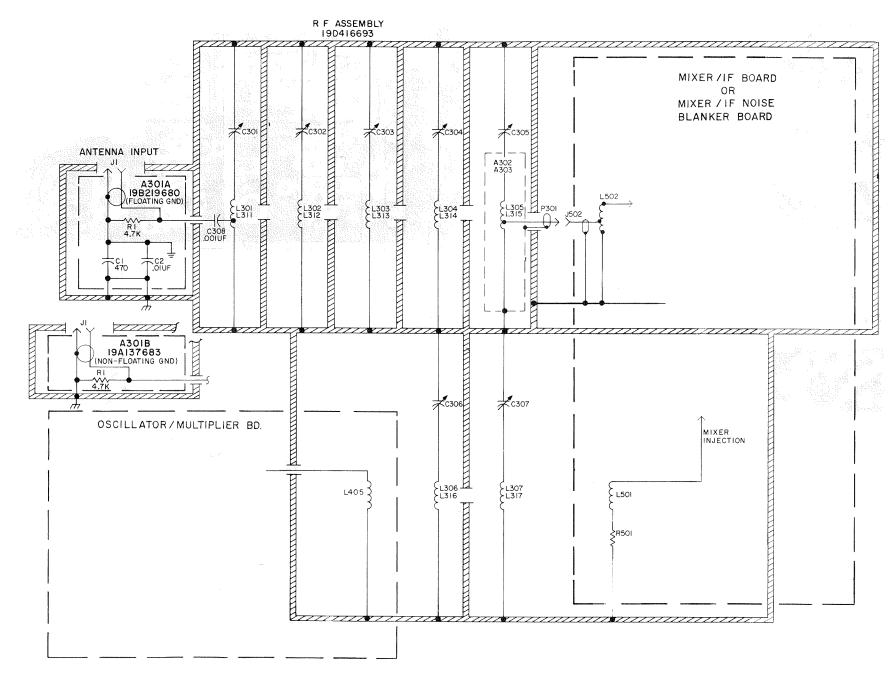
FOR 0501

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

OUTLINE DIAGRAM

138—174 MHZ RF ASSEMBLY AND MIXER/IF BOARD





ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG=1,000,000 OHMS OCAPACITOR VALUES IN PROFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF= MICROFARADS. INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H=HENRYS.

IN ORDER.TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

VOLTAGE READINGS

VOLTAGE READINGS ARE TYPICAL READINGS MEASURED TO SYSTEM NEGATIVE (P903-10) WITH TEST SET MODEL 4EX3AH OR A 20,000 OHM-PER-VOLT METER.

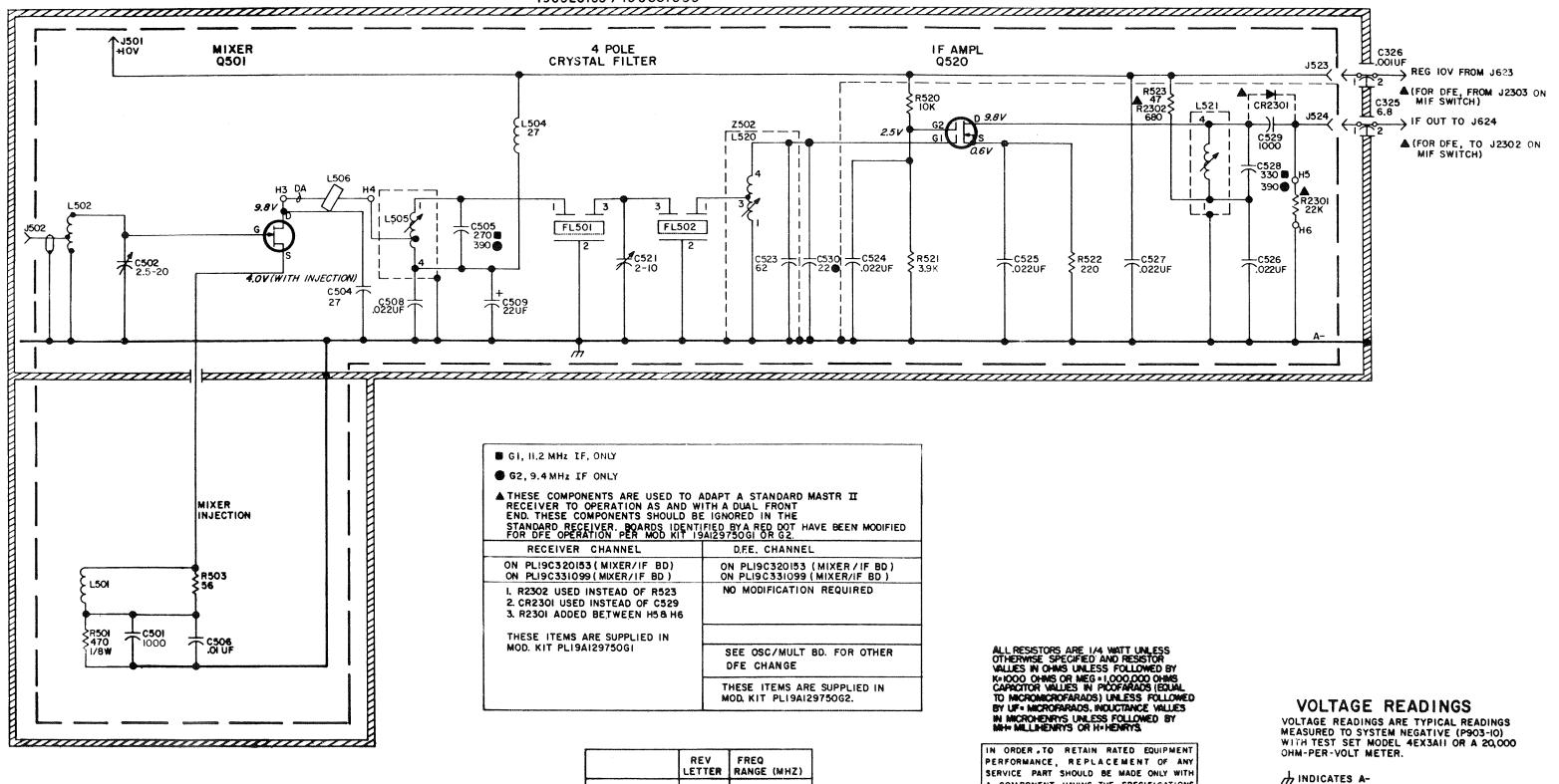
INDICATES A-

 $\stackrel{\perp}{=}$ INDICATES VEHICLE GROUND

SCHEMATIC DIAGRAM

138—174 MHZ RF ASSEMBLY

MIXER/IF BD 190320153 / 190331099



SCHEMATIC DIAGRAM

138—174 MHZ MIXER/IF BOARD

C

138-174

138 -174

MIXER/IF BD 19C320153G1

190331099

1 INDICATES VEHICLE GROUND

A COMPONENT HAVING THE SPECIFICATIONS

SHOWN ON THE PARTS LIST FOR THAT PART.

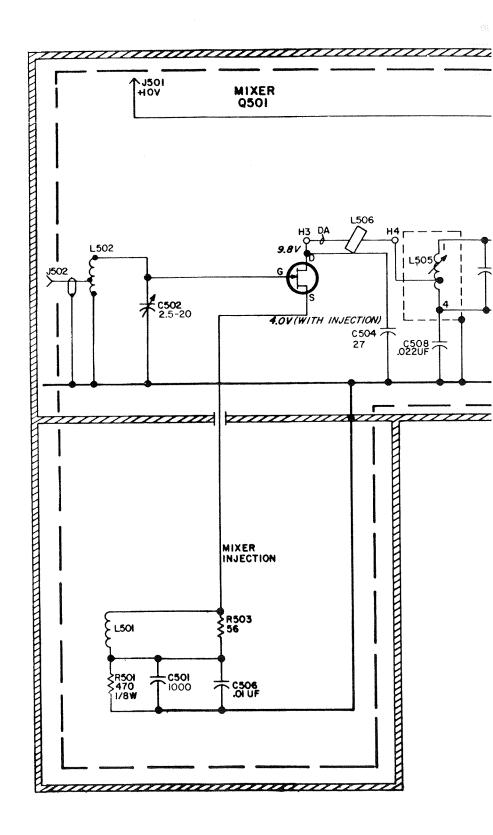
PARTS LIST

MIF ASSEMBLY 19C331099G1 ISSUE 1

SYMBOL	GE PART NO.	DESCRIPTION		
C501	19A700233P7	Ceramic: 1000 pF, $\pm 20\%$, 50 VDCW.		
C502	19A700012P2	Variable, ceramic; 2.5 to 20 pf, 200 VDCW, temp coef -250 to -700 Parts/M/°C; sim to Panasonic ECV-12M20X32.		
C504	19A143491P27KO	Ceramic: 27 pF, ±10%, 500 VDCW.		
C505	19A700105P46	Mica: 270 pF, ±5%, 0 to 70 PPM, 500 VDCW.		
C506	19A700234P7	Polyester: 0.01 μ f $\pm 10\%$, 50 VDCW.		
C508	19A700234P9	Polyester: 0.022 μ f, \pm 10%, 50 VDCW.		
C509	19A701534P8	Tantalum: 22 μ f, \pm 20%, 16 VDCw.		
C521	19A700012P1	Variable, ceramic: 2 to 10 pf, 200 VDCN, temp coef -350 to +500 PPM Parts/M/°C; sim to Panasonic ECV-1ZW10X32.		
C524 thru C527	19A143477P17	Polyester: 0.022 µf, ±20%, 50 VDCW.		
C528	5490008P139	330 pf $\pm 10\%$, 500 VDCW; sim to Electro Motive Type DM-15.		
C529	19A700233P7	Ceramic, disc: 1000 pf ±20%, 50 VDCW.		
FL501	19B219573G7	Crystal, freq: Resonator A: 11,200000 KHz, Resonator B: 11,196024 KHz, Resonator A: 11,200000 KHz, Resonator B: 11,196024 KHz.		
FL502		(Part of FL501).		
		JACKS AND RECEPTACLES		
J501	4033513P1	Contact, electrical: sim to Bead Chain L93-4.		
J502	19A130924G1	Receptacle, coaxial: sim to Cinch 14H11613.		
J523 and J524	19A116975P1	Receptacle, wire spring.		
		INDUCTORS		
L501	19A129280P1	Coil.		
L502	a100000000	Coil. (Part of printed wire board 19C331098P1).		
L504	7488079P48	Choke, RF: 27.0 μh $\pm 10\%$, 1.40 ohms DC res max; sim to Jeffers 4422-9K.		
L505	19C320141G30	Coil. Includes:		
	5493185P9	Tuning slug.		
L506	19A126140P1	Core, toroidal.		
L520		(Part of 2502).		
L521	19C320141G6	Coil. Includes;		
	5493185P9	Tuning slug.		
Q501	19A134093P1	N Type, field effect; sim to Type 2N4391.		
Q520	19A116818P1	N Channel, field effect; sim to Type 3N187.		
-				
	00151515	Generalities 470 obey #5% 1/8 W		
R501	3R151P471J	Composition: 470 ohms ±5%, 1/8 w.		
R503	19A700106P33	Composition: 56 ohms ±10%, 1/4 w.		

SYMBOL	GE PART NO.	DESCRIPTION
R520 R521 R522 R523	19A700106P87 19A700106P77 19A700106P47 19A700106P31	Composition: 10K ohms ±10%, 1/4 w. Composition: 3.9K ohms ±5%, 1/4 w. Composition: 220 ohms ±5%, 1/4 w. Composition: 47 ohms ±5%, 1/4 w.
Z 502		COIL ASSEMBLY 19C320141G20
C523	19A116114P1057	Ceramic: 62 pf ±5%, 100 VDCW; temp coef ~30 PPM.
L 520	19C320141P4 5493185P9	Coil. Tuning slug.

^{*}COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES



PARTS LIST

LB14981E

138-174 MHz RF ASSEMBLY MIF ASSEMBLY, UHS PRE-AMPLIFIER

SYMBOL	GE PART NO.	DESCRIPTION		
		RF ASSEMBLY 19D416693G1 138-155 MHz FLOATING GRD 19D416693G2 150.8-184 MHz FLOATING GRD 19D416693G7 138-155 MHz NON FLOATING GRD 19D416693G8 150.8-174 MHz NON FLOATING GRD		
A301A		ANTENNA INPUT BOARD 198219680G1		
C1	19A116679P470K	Mica: 470 pF ±10%, 250 VDCW.		
C2	19A116080P101	Polyester: 0.01 uF ±10%, 50 VDCW.		
		JACKS AND RECEPTACLES		
J1	7104941P16	Jack, phono: coaxial.		
R1	19A700106P79	Composition: 4.7K ohms ±5%, 1/4 w.		
A301B		ANTENNA INPUT PLATE 19A137683G1		
J1	7104941P20	JACKS AND RECEPTACLES Jack, phono: coaxial.		
31	7104541720	Jack, phono. coaxiai.		
R1	19A700106P79			
KI :	194700100579	Composition: 4.7K ohms ±5%, 1/4 w.		
A302 and A303		COMPONENT BOARD A302 19B226512G1 138-155 MHz A303 19B226512G2 150.8-174 MHz		
L305	19B216112G20	Coil.		
L315	19B216112G21	Coil.		
P301	5491689P85	Cable, RF: approx 4 inches long.		
C301 thru		Includes:		
C305	19C328755P3	Screw.		
	19A143476G2	Nut: thd. size No. 6-32.		
C306* and C307*		Includes:		
	19C328755P3	Screw. (Added to G2 by REV C).		
	4036765G12	Screw. (Detected in G2 by RBV C).		
C308	19A143476G2 5495581P11	Nut: thd. size No. 6-32. Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to		
C325	19B209488P1	RMC Type JR Discap. Ceramic: 6.8 pF ±20%, 500 VDCW; sim to Allen Bradley Style FA5D.		
C326	19B209488P2	Ceramic: 1000 pF -10+100%, 500 VDCW; sim to Allen Bradley Style FA5D.		
		A Company of the Comp		
L301	198216112619	Coil.		
L302	19B216112G11	Coil.		
thru L304				

SYMBOL	GE PART NO.	DESCRIPTION		
L306 and L307	19B204461G18	Coil.		
L311	198216112G17	Coil.		
L312 thru L314	19B216112G15	Coil.		
L316 and L317	19B204461G19	Coil.		
L31.7		MISCELLANEOUS		
	19E500969G1	Casting.		
	19C320251P1	Cover.		
	19B209209P305	Tap screw, Phillips POZIDRIV®: No. 6-32 x 5/16. (Secures cover).		
	19B201074P304	Tap screw, Phillips POZIDRIV®: No. 6-32 x 1/4. (Used with A301-A303).		
		MIF ASSEMBLY 19C320153G1		
C501	19A116655P19	Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.		
C502	19A700012P2	Variable, ceramic: 2.5 to 20 pF 200 VDCW, temp coef -250 -700 PPM; sim to Panasonic ECX1ZW20X32.		
C504	19A116656P27K0	Ceramic disc: 27 pF ±10%, 500 VDCW, temp coef 0 PPM.		
C505	19A700105P46	Mica: 270 pF ±5%, 500 VDCW.		
C506	19A116080P101	Polyester: 0.01 uF ±10%, 50 VDCW.		
C508	19A116080P103	Polyester: 0.022 uF ±10%, 50 VDCW.		
C509	5496267P10	Tantalum: 22 uF ±20%, 15 VDCW; sim to Sprague Type 150D.		
C521	19A700012P1	Variable, ceramic: 2 to 10 pF, 200 VDCW, temp coef -350 to +500 PPM; sim to Panasonic ECV-12W10X32.		
C523		(Part of Z502).		
C524 thru C527	19A116080P3	Polyester: 0.022 uF ±20%, 50 VDCW.		
C528	5490008P139	Silver mica: 330 pF ±10%, 500 VDCW, sim to Electro Motive Type DM-15.		
C529	19A116655P19	Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.		
FL501	19B219573G3	Crystal: Resonator A - 11,200.000;		
FL502		Resonator B - 11,196.024 kHz. (Part of FL501).		
		JACKS AND RECEPTACLES		
J501	4033513P1	Contact, electrical: sim to Bead Chain L93-4.		
J502	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to		
J523 and	19A116975P1	NTTF-1058. Contact, electrical.		
J524				
L501	19A129280P1	Coil.		
L502	es Saatte of House	Coil. (Part of printed wire board 19C321054Pl)		
L504	7488079P48	Coil, RF: 27 uH 10%, 1.4 ohms DC res. max; sim. to Jeffers 4422-9.		
L505	19C320141G30	Coil. Includes:		
L506	5493185P9 19A126140P1	Tuning slug.		
2000	**************************************	Core toroidal, ferrite: sim to Ferrocube 56-590-65A1/20.		
L520		(Part of 2502).		
L521	19C320141G6	Coil. Includes:		
RETANCOJ PARPAGOA	5493185P9	Tuning slug.		

SYMBOL	GE PART NO.	DESCRIPTION	
:		, , , , , , , , , , , , , , , , , , , ,	
Q501	19A134093P1	N Type, field effect; sim to Type 2N4391.	
Q520	19A116818P1	N Channel, field effect.	
R501	3R151P471J	Composition: 470 ohms ±5%, 1/8 w.	
R503	19A700106P33	Composition: 56 ohms ±5%, 1/4 w.	
R520	19A700106P87	Composition: 10K ohms ±5%, 1/4 w.	
R521	19A700106P77	Composition: 3.9K ohms ±5%, 1/4 w.	
R522	19A700106P47	Composition: 220 ohms ±5%, 1/4 w.	
R523	19A700106P31	Composition: 47 ohms ±5%, 1/4 w.	
Z502		COIL ASSEMBLY 19C320141G20	
C523	19A700220P57	Constitution 62 pR 45% 100 VDCW 100 TO DOW	
2020	108100220191	Ceramic: 62 pF ±5%, 100 VDCW, temp coef -30 PPM.	
1 = 00	100200111-1		
L520	190320141P4	Coil.	
	19B209674P2	Tuning slug.	
		UHS PRE-AMPLIFIER BOARD	
		19C320215G1 138-158 MHz 19C320215G2 147-174 MHz	
20004			
C2301	19A116795P250K	Mica: 250 pF ±10%, 250 VDCW.	
C2302L		(Part of T2301L).	
C2302H C2303	19A116655P19	(Part of T2301H).	
thru C2306	134110033519	Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
		JACKS AND RECEPTACLES	
J2301	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to	
		NTTF-1058.	
P2301	19A702402P2	Contact, electrical; sim to AMP 42827-2.	
P2302		(Part of W2302).	
Q2301	19A116818P1	N Channel, field effect.	
P9901	104700100707	RESISTORS	
R2301 R2303	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.	
	19A700106P87	Composition: 10K ohms ±5%, 1/4 w.	
R2304 R2305	3R152P752J 3R152P300J	Composition: 7.5K ohms ±5%, 1/4 w.	
	0.11001	Composition: 30 ohms ±5%, 1/4 w.	
T2301L		COIL ASSEMBLY 19C320141G22	
C4	5496218P308	Ceramic disc: 8 pF ±10%, 500 VDCW, temp coef	
		-150 PPM.	
L1	19C320141P25	Coil.	
	19B209674P2	Tuning slug.	

SYMBOL	GE PART NO.	DESCRIPTION
Т2301Н		COIL ASSEMBLY 19C320141G21
C5	5496218P305	
L1	19C320141P25	Coil. Tuning slug.
T2302	19A127108G1	Coil.
₩2302	5491689P85	Cable, RF: approx 4 inches long. (Includes P2302).
	19B219470P2	Shield.
	19A129424G1 4031594P1	Can. (Used with L505, L521, Z502 and T2301 on PRE-AMPLIFIER Board). Insulator. (Located under C502, C521).
	4035306P23	Washer, fiber. (Located under J502).
	4035306P11	Washer, fiber: 1/8 dia. (Located under Q520).
	·	RECEIVER MODIFICATION KIT 19A129750G1
CR2301	19A116925P1	
R2301	194700106P95	
R2302	19A700106P59	Composition: 22K ohms ±5%, 1/4 w. Composition: 680 ohms ±5%, 1/4 w.
₩2301	19B219999G2	Cable, RF: approx 1 foot long. Includes: (1) 5496078P2 connector.
		DFE MODIFICATION KIT 19A129750G2
		}

DESCRIPTION	SYMBO	L GE PART NO.	DESCRIPTION
8	1		
oil.			
oil.	Q501	19A134093P1	N Type, field effect; sim to Type 2N4391.
211.	Q520	19A116818P1	N Channel, field effect.
311.			RESISTORS
oil.	R501	3R151P471J	Composition: 470 ohms <u>+</u> 5%, 1/8 w.
	R503	19A700106P33	Composition: 56 ohms ±5%, 1/4 w.
MISCELLANEOUS	R520	19A700106P87	Composition: 10K ohms ±5%, 1/4 w.
isting.	R521	19A700106P77	Composition: 3.9K ohms ±5%, 1/4 w.
over.	R522	19A700106P47	Composition: 220 ohms $\pm 5\%$, $1/4$ w.
ip screw, Phillips POZIDRIV®: No. 6-32 x 5/16. Secures cover).	R523	19A700106P31	Composition: 47 ohms $\pm 5\%$, $1/4$ w.
ip screw, Phillips POZIDRIV®: No. 6-32 x 1/4. Jsed with A301-A303).			NETWORKS
MIF ASSEMBLY 19C320153G1	Z502		COIL ASSEMBLY 19C320141G20
eramic disc: 1000 pF ±20%, 1000 VDCW; sim to	C523	19A700220P57	Ceramic: 62 pF ±5%, 100 VDCW, temp coef -30 PPM.
triable, ceramic: 2.5 to 20 pF 200 VDCW, tempor -250 -700 PPM; sim to Panasonic ECX12W20X32.			
er -250 -700 PPM; sim to Panasonic ECX1ZW20X32.	L520	19C320141P4	Coil.
PPM.	estige of	19B209674P2	Tuning slug.
.ca: 270 pF +5%, 500 VDCW.			UHS PRE-AMPLIFIER BOARD
olyester: 0.01 uF ±10%, 50 VDCW.			19C320215G1 138-158 MHz 19C320215G2 147-174 MHz
olyester: 0.022 uF ±10%, 50 VDCW. Intalum: 22 uF ±20%, 15 VDCW; sim to Sprague		.ii	
'pe 150D.		10111650500500	
riable, ceramic: 2 to 10 pF, 200 VDCW, temp pef -350 to +500 PPM; sim to Panasonic	C2301 C2302L	19A116795P250K	Mica: 250 pF ±10%, 250 VDCW.
V-1ZW10X32.	1 1		(Part of T2301L).
'art of Z502).	C2302H C2303	19A116655P19	(Part of T2301H).
olyester: 0.022 uF ±20%, 50 VDCW.	thru C2306		Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
lver mica: 330 pF $\pm 10\%$, 500 VDCW, sim to ectro Motive Type $D\overline{M} = 15$.	l grand		JACKS AND RECEPTACLES
ramic disc: 1000 pF ±20%, 1000 VDCW; sim to	J2301	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058.
IC Type JF Discap.	4 4 3		
ystal: Resonator A - 11,200.000;	P2301 P2302	19A702402P2	Contact, electrical; sim to AMP 42827-2.
ystal: Resonator A - 11,200.000; sonator B - 11,196.024 kHz. 'art of FL501).	P2302		(Part of W2302).
'art of FL501).	e les	1	TRANSISTORS
	Q2301	19A116818P1	N Channel, field effect.
ntact, electrical: sim to Bead Chain L93-4.		The state of the s	RESISTORS
nnector, receptacle; 500 VDCW maximum; sim to	R2301	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
Minute electrical	R2303	19A700106P87	Composition: 10K ohms ±5%, 1/4 w.
A WARRANT	R2304	3R152P752J	Composition: 7.5K ohms ±5%, 1/4 w.
	R2305	3R152P300J	Composition: 30 ohms ±5%, 1/4 w.
41.			TRANSFORMER
il. (Part of printed wire board 19C321054P1)			TRANSFORMERS
il, RF: 27 uH 10%, 1.4 ohms DC res. max; sim. Jeffers 4422-9.	T2301L		COIL ASSEMBLY 19C320141G22
il. Includes:	and the same of th		
ning slug.	C4	5496218P308	Ceramic disc: 8 pF ±10%, 500 VDCW, temp coef
re toroidal, ferrite: sim to Ferrocube -590-65A1/20.			-150 PPM.
art of Z502).			
il. Includes:	L1	19C320141P25	Coil.
ning slug.		19B209674P2	Tuning slug.

SYMBOL	GE PART NO.	DESCRIPTION
Т2301Н		COIL ASSEMBLY 19C320141G21
C5	5496218P305	Ceramic disc: 5.0 pF ±10%, 500 VDCW, temp coef -150 PPM.
	100000111705	
L1	19C320141P25 19B209674P2	Coil. Tuning slug.
T2302	19A127108G1	Coil.
₩2302	5491689P85	Cable, RF: approx 4 inches long. (Includes P2302).
		MISCELLANEOUS
	19B219470P2 19A129424G1	Shield.
		Can. (Used with L505, L521, Z502 and T2301 on PRE-AMPLIFIER Board).
	4031594P1 4035306P23	Insulator. (Located under C502, C521). Washer, fiber. (Located under J502).
	4035306P11	Washer, fiber: 1/8 dia. (Located under Q520).
		RECEIVER MODIFICATION KIT 19A129750G1
CR2301	19A116925P1	DIODES AND RECTIFIERS
CR2301	19411092571	
R2301	19A700106P95	
R2302	19A700106P59	Composition: 680 ohms ±5%, 1/4 w.
/2301	19B219999G2	Cable, RF: approx 1 foot long. Includes: (1) 5496078P2 connector.
		DFE MODIFICATION KIT 19A129750G2

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A thru C - Mixer/IF Board 19C320153G1

REV. A and B \sim RF Assembly 19D416693G1,2

REV. A and B - Preamplifier Assembly 19C320215Gl,2

Incorporated in initial shipment.

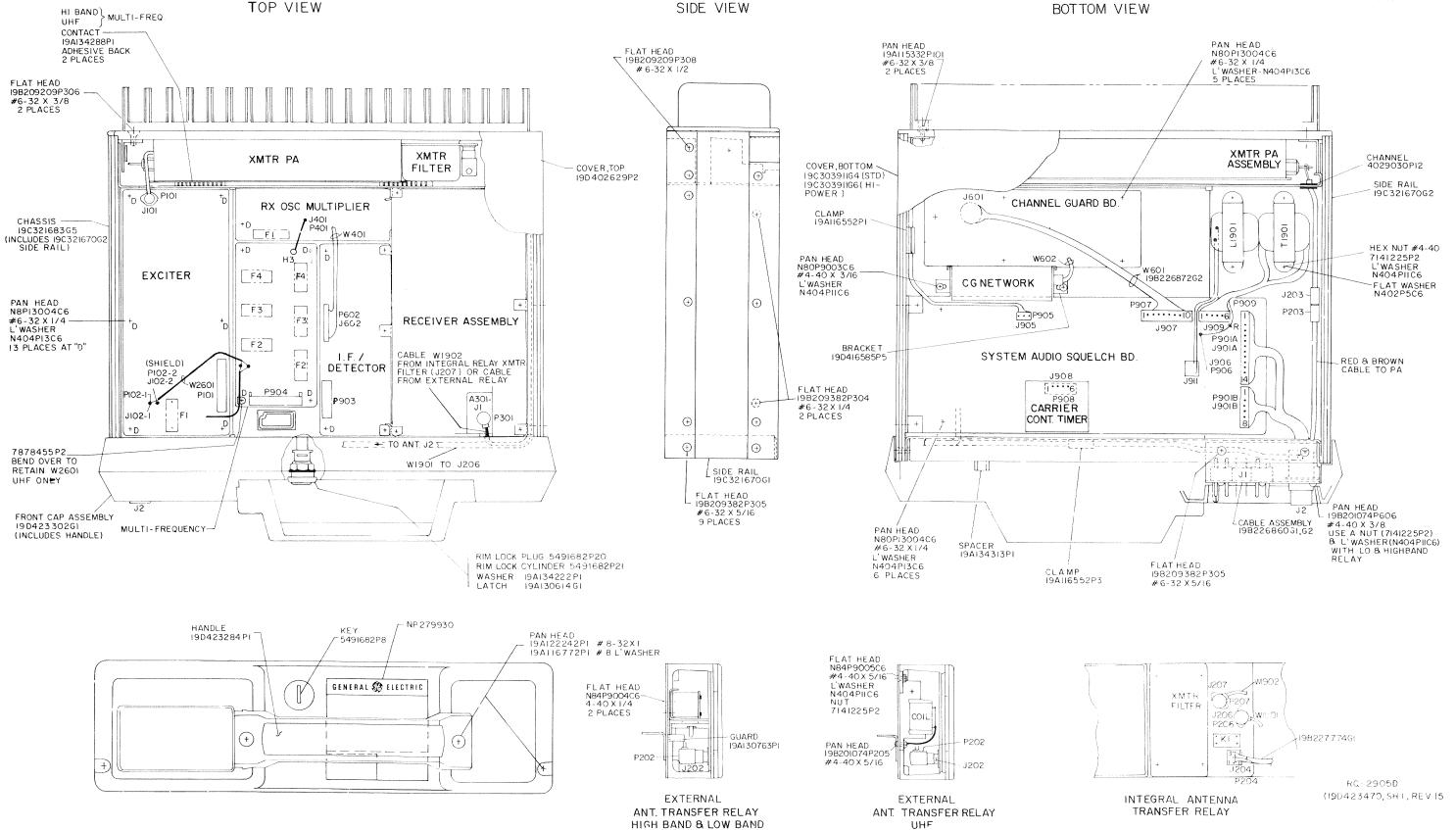
REV. C - RF Assembly 19D416693G2

To improve band end tuning. Changed C306 and C307.





TOP VIEW



MECHANICAL PARTS BREAKDOWN

MAIN CHASSIS